

Primary-Side-Controlled, Offline LED Driver with Fully-Integrated Internal MOSFET

The Future of Analog IC Technology

DESCRIPTION

The MP4032-1 is a TRIAC-dimmable, primaryside-controlled, offline, LED lighting driver with an integrated 500V MOSFET. It can achieve a high power factor and accurate LED current control for lighting applications in a single-stage converter. The proprietary real-current control can accurately control the secondary-side LED current using primary-side information. It simplifies LED lighting systems and increases efficiency by removing the secondary feedback components and the current-sensing resistor.

The MP4032-1 has a power-factor-correction function and works in boundary-conduction mode that reduces power losses. The DRAIN pin can supply current to the internal charging circuit for start-up without a perceptible delay. The proprietary dimming control extends the TRIAC-based dimming range.

The multiple protections greatly enhance system reliability and safety. These protections include VCC under-voltage lockout, LED overvoltage and over-current protections, shortcircuit protection, and over-temperature protection.

The MP4032-1 is available in an SOIC8-7A package.

FEATURES

- Real Current Control without Secondary Feedback Circuit
- Internal MOSFET with 500V High Voltage Rating
- Less than 6W Output Power
- Internal Charging Circuit for Fast Start-Up
- Accurate Line Regulation
- Flicker-Free, Phase-Controlled TRIAC Dimming with Extended Dimming Range
- High Power Factor
- Boundary-Conduction Mode
- VCC UVLO
- Cycle-by-Cycle Current Limiting
- Over-Voltage Protection
- Short-Circuit Protection
- Over-Temperature Protection
- Available in SOIC8-7A Package

APPLICATIONS

- Solid-State Lighting
- Industrial and Commercial Lighting
- Residential Lighting

All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Products, Quality Assurance page.

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The MP4032-1 is patent pending.

Warning: Although this board is designed to satisfy safety requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype High Voltage board.

TYPICAL APPLICATION

ORDERING INFORMATION

* For Tape & Reel, add suffix –Z (e.g. MP4032-1GS–Z)

PACKAGE REFERENCE

ABSOLUTE MAXIMUM RATINGS (1)

Recommended Operating Conditions (3)

Thermal Resistance (4) *θJA θJC*

SOIC8-7A................................96 45... °C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature $T_J(MAX)$, the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_D(MAX)=(T_J(MAX)-T_J(MAX)-T_J(MAX)-T_J(MAX)-T_J(MAX)$ T_A)/ θ_{JA} . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operation conditions.
- 4) Measured on JESD51-7 4-layer board.

ELECTRICAL CHARACTERISTICS

 V_{CC} = 16V, T_A = +25°C, unless otherwise noted.

ELECTRICAL CHARACTERISTICS *(continued)*

 V_{CC} = 16V, T_A = +25°C, unless otherwise noted.

Notes:

5) The multiplier output is given by: $V_{CS} = K \cdot V_{MULT} \cdot (V_{COMP} - 1.5)$

6) Guaranteed by design.

TYPICAL CHARACTERISTICS

The Curve of Multiplier Gain (K)

Multiplier Gain (K) vs. **Junction Temperature**

Minimum Off Time vs. **Junction Temperature**

TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN}=120VAC, I₀=350mA, V₀=18V, 6LEDs in series, L_m=2.6mH, N_p:N_s:N_{aux}=96:16:20, TRIAC **dimmable, without ripple suppressor.**

Dimming Curve Conducted EMI CDN

Efficiency vs. V_{IN} PF vs. V_{IN} THD vs. V_{IN} THD vs. V_{IN}

 V_{IN} (VAC)

EFFICIENCY (%)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

V_{IN}=120VAC, I₀=350mA, V₀=18V, 6LEDs in series, L_m=2.6mH, N_p:N_s:N_{aux}=96:16:20, TRIAC **dimmable, without ripple suppressor.**

Steady State

Short Circuit Protection

V_{IN} Start Up

MONOCOMMENT DE L'ANTIQUE

40ms/div.

Over Voltage Protection LED Load Open When Working

Triac Dimming Triac Dimming Triac Dimming $DUTY = 60%$ $DUTY = 40%$ $DUTY = 20%$ V_{COMP} V_{COMP} V_{COMP} 1V/div. 1V/div. 1V/div. I LED I_{LED}
.10mA/div l_{LED}
.100mA/div 50mA/div. V_{MULT}
1V/div. V_{MULTI} V_{MULT}
1V/div. 1V/div. I_{IN}
.200mA/div I_{IN}
.200mA/div I_{IN}
.200mA/div 4ms/div. 4ms/div 4ms/div

I LED 200mA/div.

V_{COMP}
2V/div.

V_{DRAIN}
200V/div.

 V_{CC}
10V/div.

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PIN FUNCTIONS

FUNCTION DIAGRAM

Figure 1: Functional Block Diagram

OPERATION

The MP4032-1 is a TRIAC-dimmable, primaryside-controlled, offline, LED driver with an integrated high-voltage MOSFET. It incorporates multiple features specifically for highperformance LED lighting. It uses a realcurrent-control method using primary-side information to accurately control LED current. It can achieve a high power factor to eliminate pollution on the AC-line.

System Start-Up and Power Supply

The VCC pin supplies power to both the control signal and the gate drive signal. After connecting the AC line, the VCC capacitor charges from the DRAIN pin through an internal high-voltage DRAIN charger. Once VCC reaches 13.8V, the control logic initiates and the gate drive signal forces the integrated high-voltage power MOSFET to begin switching for normal operation. Meanwhile, the DRAIN charger stops. The auxiliary winding takes over the power supply after charging.

If V_{CC} drops below 9.4V without fault, the DRAIN charger resumes function to charge V_{CC} back to 13.8V. If a fault occurs, the system stops switching and the auto-restart function activates once V_{cc} drops to 7.5V.

Power-Factor Correction

The MULT pin connects to the tap of the resistor divider from the rectified instantaneous line voltage. It is one of the inputs of the Multiplier. The multiplier's output has a sinusoidal shape. This signal provides the reference for the current comparator, and is compared with the primaryside inductor current sensed by the CS pin: The CS pin shapes the primary-peak-current envelope sinusoid to match the input line voltage. This control method can achieve a high power factor.

Figure 2: Power-Factor Correction

The maximum voltage of the multiplier output to the current comparator is clamped to 2.27V to limit the cycle-by-cycle current.

Boundary-Conduction Mode

During the internal MOSFET ON time (τ_{ON}) , the rectified input voltage (V_{BUS}) applies to the primary-side inductor (L_m) , and the primary current (I_{pri}) increases linearly from zero to the peak value (I_{ok}) . When the internal MOSFET turns off, the energy stored in the inductor transfers to the secondary side and turns on the secondary-side diode to power the load. The secondary current (I_{sec}) then decrease linearly from the peak value to zero. When the secondary current reaches zero, the primary-side leakage inductance, magnetizing inductance and all the parasitic capacitances decrease the MOSFET drain-source voltage—this decrease is also reflected on the auxiliary winding (see Figure 3). The zero-current detector on the ZCD pin generates the internal MOSFET's turn-on signal when the ZCD voltage falls below 0.35V, and ensures that the MOSFET turns on at a valley voltage (see Figure 4).

Figure 3: Boundary-Conduction Mode

Figure 4: Zero-Current Detector

As a result, there are virtually no primary switch turn-on losses and no secondary diode reverserecover losses. It ensures high efficiency and low EMI noise.

Real-Current Control

The proprietary real-current control allows the MP4032-1 to control the secondary-side LED current by sampling the primary-side information through the CS sensing resistor. The mean output LED current is approximately:

$$
I_o \approx \frac{N \cdot V_{FB}}{2 \cdot R_s}
$$

Where:

N is the turn ratio of primary side to secondary side

 V_{FB} is the internal reference voltage (typically 0.403V)

 R_s is the sensing resistor connected between the CS pin and GND.

Auto Start

The MP4032-1 integrates an auto starter. The starter begins a timer when the MOSFET turns on. If ZCD fails to send out another turn-on signal after 130µs, the starter will automatically send a turn-on signal to avoid unnecessary IC shutdowns from a missed zero-current detection.

Minimum Off Time

The MP4032-1 operates with variable switching frequency. The frequency changes with the instantaneous input line voltage. To limit the maximum frequency and improve EMI performance, the MP4032-1 employs an internal minimum off-time limiter, with a minimum off-time of 5.6µs.

Leading-Edge Blanking

An internal leading-edge blanking (LEB) unit is employed between the CS pin and the current comparator input to prevent the switching pulse from prematurely terminating due to parasitic capacitance discharge when the MOSFET turns on. During the blanking time, the path from the CS pin to the current comparator input is blocked. Figure 5 shows the leading-edge blanking.

Figure 5: Leading-Edge Blanking

Output Over-Voltage Protection (OVP)

Output over-voltage protection can prevent component damage during an over-voltage condition. Since the auxiliary winding's positive voltage plateau is proportional to the output voltage, OVP uses the auxiliary winding voltage through the ZCD over-voltage detector instead of directly monitoring the output voltage. The OVP sampling unit is shown in Figure 6. Once the ZCD pin voltage exceeds 5.3V, the OVP signal triggers and latches, the gate driver turns off, and the IC functions in quiescent mode until the VCC voltage drops to 7.5V, which causes the system to restart. The output OVP setting point can be calculated as:

$$
V_{\text{OUT_OVP}} \cdot \frac{N_{\text{AUX}}}{N_{\text{SEC}}} \cdot \frac{R_{\text{ZCD2}}}{R_{\text{ZCD1}} + R_{\text{ZCD2}}} = 5.3V
$$

 $V_{\text{OUT OVP}}$ is the output over-voltage protection threshold,

 N_{AUX} is the number of auxiliary winding turns

 N_{SEC} is the number of secondary winding turns.

Figure 6: Over-Voltage Sampling Unit

To avoid an oscillation spike mis-triggering the OVP after the switch turns off, the OVP has a blanking period, as shown in Figure 7. The blanking period ($\tau_{LEB-OVP}$) is typically 1.9µs.

Figure 7: ZCD Voltage and OVP Sampling

Over-Current Protection

The MP4032-1 clamps the CS pin voltage \leq 2.27V to limit the available output power. If a short circuit on the secondary-side occurs, the ZCD pin can't detect the zero-crossing signal and triggers a 130µs auto-restart process. The COMP voltage drops and the primary-side-peak current falls, thus limiting the SC current. Meanwhile, the auxiliary winding voltage falls following the secondary winding voltage, V_{CC} drops below 9.4V, and the system restarts. Furthermore, once the COMP level exceeds 5V, the COMP OCP triggers and the system stops switching until V_{CC} drops to 7.5V UVLO, and the system autorestarts.

Thermal Shutdown

To prevent thermal damage, the MP4032-1 shuts off switching and remains latched once the inner temperature exceeds the OTP threshold. When $V_{\rm CC}$ drops below 7.5V, the system restarts.

TRIAC-Phase Dimming

The MP4032-1 can implement TRIAC-based dimming. As shown in Figure 8, the TRIAC dimmer is a bi-directional SCR with an adjustable turn-on phase. The MP4032-1 detects the dimming phase signal on the MULT pin that feeds the signal into the control loop for the dimming control.

Figure 8: TRIAC-Phase Detection Signal for a Leading-Edge TRIAC Dimmer

APPLICATION INFORMATION

Components Selection

(Please refer to Application Note *AN055* **for detailed design)**

Input EMI Filter

Select EMI component values to pass EMI test standards, as well as to account for the power factor and inrush current when dimming turns on. The input capacitance plays a primary role: a small input capacitance can increase the power factor and decrease the inrush current, so select a relatively small X capacitor.

Input Bridge

The input bridge can use standard, slow-recovery, low-cost diodes. When selecting diodes, take into account these three items: the maximum input RMS current; the maximum-input-line voltage; and thermal performance.

Input Capacitor

The input capacitor mainly provides the transformer's switching frequency magnetizing current. The maximum current occurs at the peak of the input voltage. Limit the capacitor's maximum high-frequency voltage ripple to 10%, or the voltage ripple may cause more primarypeak-current spikes and degrade both the power loss and the EMI performance.

$$
C_{\text{in}} > \frac{I_{\text{pk_max}} - \sqrt{2} I_{\text{pri_rms_max}}}{2 \cdot \pi \cdot f_{s_min} \cdot V_{\text{ac_min}} \cdot 0.1}
$$

Input capacitor selection requires taking into account the EMI filter, the power factor, and the surge current at the dimming turn-on time. A large capacitor improves EMI, but limits the power factor and increases the inrush current.

Passive Bleeder and Active Damper

Since the LED lamp impedance is relatively large, significant ringing occurs when the leading-edge TRIAC dimmer turns on due to an inrush current charging the input capacitance. The ringing may cause the TRIAC current to fall below the holding current and turn off the TRIAC dimmer, which can cause flickering.

The typical application circuit incorporates both a

passive bleeder and an active damping circuit to address this issue. The design details can be found in the corresponding design tools.

Transformer

After accounting for the ratings of the primary MOSFET and the secondary rectifier diode, some applications allow for a range of turn ratios N to be selected, which then requires the following considerations: a small N leads to a poor THD; a large N leads to a larger primary inductance and a physically larger transformer.

Usually, the system will define a minimum frequency f_s _{min} at the peak of $V_{ac,min}$. So setting the value of f_s _{min} can get the primary inductance L_P . The design details can also be found in the design tools.

RCD Snubber

The peak voltage across the MOSFET at turn-off includes the instantaneous input-line voltage, the voltage reflected from the secondary side, and the voltage spike due to the leakage inductance. The RCD snubber protects the MOSFET from over-voltage damage by absorbing the leakage inductance energy and clamping the drain voltage. The design details can be found in the corresponding design tools.

Secondary Rectifier Diode

Choose a diode with an appropriate reversevoltage rating and current rating. The reverse recovery of the freewheeling diode can affect the efficiency and circuit operation, and a Schottky or ultra-fast diode is recommended.

Output Capacitor

The output voltage ripple has two components: the switching-frequency ripple associated with the flyback converter, and the low-frequency ripple associated with the input-line voltage (120Hz). Selecting the output bulk capacitor depends on the LED current ripple, the allowable overvoltage and the desired voltage ripple.

Meanwhile, a pre-load resistor is necessary to discharge the output voltage under open-load conditions.

MULT Pin Resistor Divider

The MULT pin resistor divider requires careful tuning because the MULT voltage determines the COMP voltage level, which directly influences the dimming curve and performance. Test the estimated divider values with different types of TRIAC dimmers to determine precise resistor values: typically use the divider for a COMP level of 2.3V at 120VAC input.

Add a ceramic X7R capacitor to the MULT pin to absorb the switching-frequency ripple on the MULT voltage for accurate dimming-phase detection. Increasing the capacitance can further smooth the MULT voltage, but increase the inputline voltage phase shift and diminish the power factor. Typical values are between 2.2nF and 8.2nF.

VCC Power Supply

After the system starts up, the auxiliary winding takes over the VCC power supply through a rectifying diode with a relatively small currentlimiting resistor because of the limited power dissipation. The bulk capacitor stabilizes the VCC voltage to limit the ripple—most applications use 22μF. Use the following equation to determine the voltage rating of the rectifying diode:

$$
V_{\text{D}} > \text{VCC}_{\text{max}} + \frac{N_{\text{aux}}}{N_{\text{p}}} \cdot V_{\text{in_max}} + V_{\text{aux_negative_spike}}
$$

Where VCC_{max} is the maximum VCC voltage, typically 27V, N_{aux} and N_{p} are the auxiliary winding and primary winding turns, V_{aux negtive spike} is the maximum negative spike on auxiliary winding.

Layout Guide

PCB layout is very important to achieve reliable operation, and good EMI and thermal performance. Follow these guidelines to optimize performance.

- 1) Design a short main-power path. Directly connect the sense resistor GND return to the input capacitor. Use the largest-possible copper pour for the power devices for good thermal performance.
- 2) Separate the power GND and the analog GND, and connect them together only at an IC GND pin.
- 3) Place the components as close as possible to the corresponding IC pins. The ZCD pin bypass capacitor and the COMP pin capacitor have priority.
- 4) Isolate the primary-side and the secondaryside by at least 6mm to meet safety requirements and the Hipot test. Adjust the transformer installation position to keep the primary side far away from secondary side.
- 5) Separate the input high voltage wire from other components and GND to avoid surge failures. Select the pull-down resistors for the BUS line to the active damping circuit and the MULT pin for the DIP package.
- 6) On the secondary side, place the rectifying diode as close as possible to the output filter capacitor, and use a short trace from the transformer output return pin to the return point of the output filter capacitor.

RIPPLE SUPPRESSOR

(Innovative Proprietary)

For dimming LED lighting application, a single stage PFC converter needs large output capacitor to reduce the ripple whose frequency is double of the Grid. And in deep dimming situation, the LED would have shimmer caused by the dimming on duty which is not all the same in every line cycle. What's more, the Grid has noise or inrush which would bring out shimmer even flicker. Figure 9 shows a ripple suppressor, which can shrink the LED current ripple obviously.

Figure9: Ripple Suppressor

Principle

Shown in Figure 9, Resister R, capacitor C, and MOSFET M compose the ripple suppressor. Through the RC filter, C gets the mean value of the output voltage V_{C_0} to drive the MOSFET M. M works in variable resistance area. C's voltage V_c is steady makes the LEDs voltage is steady, so the LEDs current will be smooth. MOSFET M holds the ripple voltage v_{Co} of the output.

Diode D and Zener diode D_z are used to restrain the overshoot at start-up. In the start-up process, through D and D_z , C is charged up quickly to turn on M, so the LED current can be built quickly. When V_c rising up to about the steady value, D and D_z turn off, and C combines R as the filter to get the mean voltage drop of V_{Co} .

The most important parameter of MOSFET M is the threshold voltage V_{th} which decides the power loss of the ripple suppressor. Lower V_{th} is better if the MOSFET can work in variable resistance area. The BV of the MOSFET can be selected as double as V_{Co} and the Continues Drain current level can be selected as decuple as the LEDs' current at least.

About the RC filter, it can be selected by $\tau_{\text{RC}} \ge 50 / f_{\text{LineCycle}}$. Diode D can select 1N4148,

and the Zener voltage of D_z is as small as possible when guarantee $\mathsf{V}_{\mathsf{D}} + \mathsf{V}_{\mathsf{DZ}} > 0.5 \cdot \mathsf{V}_{\mathsf{C}_{\mathsf{O_PP}}}\,.$

Optional Protection Circuit

In large output voltage or large LEDs current application, MOSFET M may be destroyed by over-voltage or over-current when LED+ shorted to LED- at working.

Gate-Source(GS) Over-voltage Protection

Figure 10: Gate-Source OVP Circuit

Figure 10 shows GS over-voltage protection circuit. Zener diode D_G and resistor R_G are used to protect MOSFET M from GS over-voltage damaged. When LED+ shorted to LED- at normal operation, the voltage drop on capacitor C is high, and the voltage drop on Gate-Source is the same as capacitor C. The Zener diode D_G limits the voltage V_{GS} and R_G limits the charging current to protect D_G . R_G also can limit the current of D_Z at the moment when LED+ shorted to LED-. V_{DG} should bigger than V_{th} .

Drain-Source Over-voltage and Over-current Protection

As Figure 11 shows, NPN transistor T, resistor R_C and R_F are set up to protect MOSFET M from over-current damaged when output short occurs at normal operation. When LED+ shorted to LED-, the voltage v_{DS} of MOSFET is equal to the v_{Co} which has a high surge caused by the parasitic parameter. Zener Dioder D_{DS} protects MOSFET from over-voltage damaged. Transistor T is used to pull down the V_{GS} of M. When M turns off, the load is opened, then the OVP mode is triggered,

and the IC functions in quiescent. The pull down

point is set by R_c and R_E: $R_c/R_E \cdot \frac{V_{\text{CO}}}{2} = 0.7V$.

In the Table 1, there are some recommended MOSFET for ripple suppressor.

Figure 11: Drain-Source OVP and OCP Circuit

Table 1: MOSFET LIST

TYPICAL APPLICATION CIRCUITS

Figure 12: 108VAC-132VAC/60Hz Input Flyback Converter with an 18V/350mA Output **for TRIAC-Dimmable Lighting**

PACKAGE INFORMATION

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